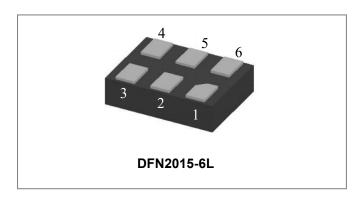






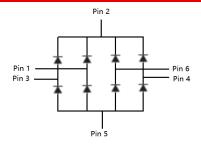
# BAT54DF SURFACE MOUNT SCHOTTKY BARRIER DIODE



#### **Features**

- Low Turn-on Voltage
- Fast Switching
- PN Junction Guard Ring Transient and ESD Protection
- Designed for Surface Mount Application
- Plastic Material —UL Recognition Flammability Classification 94V-O
- Green Products in Compliance with the ROHS Directive
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

#### **Schematic & Pin Configuration**



#### **Mechanical Characteristics**

- Case: DFN2015-6L, Molded plastic
- Terminals: Plated Leads Solderable per MIL-STD-202, Method 208

#### Maximum Ratings @TA=25°C unless otherwise specified

Characteristic	Symbol	Value	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V <sub>RRM</sub> V <sub>RWM</sub> V <sub>R</sub>	30	V
Continuous Forward Current	lo	100	mA
Forward Continuous Current	I <sub>FM</sub>	200	mA
Repetitive Peak Forward Current @ t $\leq$ 1s, $\delta \leq$ 0.5	I <sub>FRM</sub>	300	mA
Non-Repetitive Peak Forward Surge Current @t=8.3ms	I <sub>FSM</sub>	600	mA
Power Dissipation	P <sub>D</sub>	410	mW
Thermal Resistance, Junction to Ambient	R <sub>θJA</sub>	305	°C/W
Junction and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-55 to +150	°C

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#### Electrical Characteristics @T<sub>A</sub>=25°C unless otherwise specified

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop*					
Pin1 to Pin2; Pin3 to Pin2;					
Pin4 to Pin2; Pin6 to Pin2;	$V_{F1}$	@ 200uA, Pulse, T <sub>J</sub> = 25 °C	0.26	0.30	V
Pin5 to Pin1; Pin5 to Pin3;					
Pin5 to Pin4; Pin5 to Pin6;					
Reverse Current*					
Pin1 to Pin2; Pin3 to Pin2;		@V <sub>R</sub> = 30V, Pulse, T <sub>J</sub> = 25 °C	0.7	1	
Pin4 to Pin2; Pin6 to Pin2;	I <sub>R1</sub>	$@V_R = 3.3V$ , Pulse, $T_J = 60  ^{\circ}C$	0.7	2	μA
Pin5 to Pin1; Pin5 to Pin3;		@v <sub>R</sub> = 3.3v, Fulse, I <sub>J</sub> = 60°C	0.4	_	
Pin5 to Pin4; Pin5 to Pin6;					
Capacitance between terminals					
Pin1 to Pin2; Pin3 to Pin2;					
Pin4 to Pin2; Pin6 to Pin2;	C⊤	$@V_R = 1 \text{ V, Tc}=25, f_{SIG} = 1MHz$	5	10	pF
Pin5 to Pin1; Pin5 to Pin3;					
Pin5 to Pin4; Pin5 to Pin6;					

 $<sup>^*</sup>$  Pulse width < 300  $\mu$ s, duty cycle < 2%

#### **Ordering Information**

Device	Package	Shipping	
BAT54DF	DFN2015-6L	3000pcs/reel	

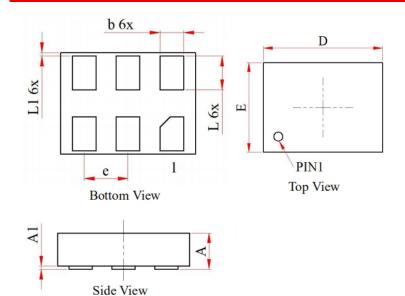
For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

#### **Marking Diagram**



DF = Marking Code

#### **Mechanical Dimensions DFN2015-6L**



OVMDOL	Millimeters			
SYMBOL	Normal	MIN.	MAX.	
А	-	0.500	0.600	
A1	-	0.025	0.075	
D	2.000	1.900	2.100	
E	1.500	1.400	1.600	
b	0.350	0.300	0.400	
L	0.500	0.450	0.550	
L1	0.050	0.010	0.090	
е	0.650 BSC			

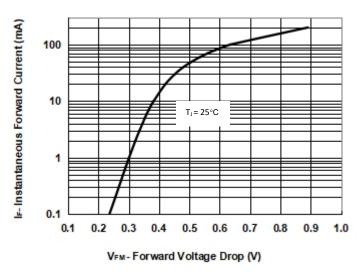
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### **Ratings and Characteristics Curves**



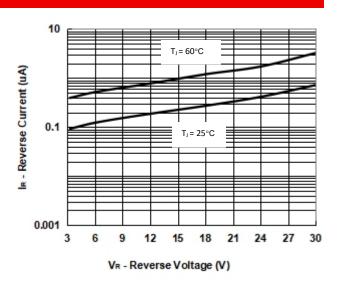


Fig. 1 - Typical Forward Characteristics

Fig. 2 - Typical Reverse Characteristics

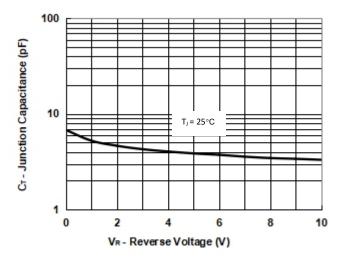


Fig. 3 - Typical Junction Capacitance







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